Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.338 inches
Overall Diameter:
0.625 inches
Electrode Internally-electrically Connected To Case:
Cathode
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
400.0 repetitive peak reverse voltage and 280.0 reverse voltage, total rms and 450.0 nonrepetitive peak reverse voltage
Current Rating Per Characteristic:
50.00 amperes forward current, average absolute
Maximum Operating Tempurature Per Measurement Point:
195.0 degrees celsius junction
Terminal Type And Quantity:
1 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0